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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	540
Number of Logic Elements/Cells	4320
Total RAM Bits	94208
Number of I/O	104
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	132-LFBGA, CSPBGA
Supplier Device Package	132-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo2-4000he-6mg132c

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



This phase shift can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after a phase adjustment on the output used as the feedback source and not relock until the  $t_{I,OCK}$  parameter has been satisfied.

The MachXO2 also has a feature that allows the user to select between two different reference clock sources dynamically. This feature is implemented using the PLLREFCS primitive. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

The MachXO2 PLL contains a WISHBONE port feature that allows the PLL settings, including divider values, to be dynamically changed from the user logic. When using this feature the EFB block must also be instantiated in the design to allow access to the WISHBONE ports. Similar to the dynamic phase adjustment, when PLL settings are updated through the WISHBONE port the PLL may lose lock and not relock until the t<sub>LOCK</sub> parameter has been satisfied. The timing parameters for the PLL are shown in the sysCLOCK PLL Timing table.

For more details on the PLL and the WISHBONE interface, see TN1199, MachXO2 sysCLOCK PLL Design and Usage Guide.



#### Figure 2-7. PLL Diagram

Table 2-4 provides signal descriptions of the PLL block.

Table 2-4. PLL Signal	Descriptions
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Port Name	I/O	Description
CLKI	I	Input clock to PLL
CLKFB	I	Feedback clock
PHASESEL[1:0]	I	Select which output is affected by Dynamic Phase adjustment ports
PHASEDIR	I	Dynamic Phase adjustment direction
PHASESTEP	I	Dynamic Phase step – toggle shifts VCO phase adjust by one step.



# Programmable I/O Cells (PIC)

The programmable logic associated with an I/O is called a PIO. The individual PIO are connected to their respective sysIO buffers and pads. On the MachXO2 devices, the PIO cells are assembled into groups of four PIO cells called a Programmable I/O Cell or PIC. The PICs are placed on all four sides of the device.

On all the MachXO2 devices, two adjacent PIOs can be combined to provide a complementary output driver pair.

The MachXO2-640U, MachXO2-1200/U and higher density devices contain enhanced I/O capability. All PIO pairs on these larger devices can implement differential receivers. Half of the PIO pairs on the top edge of these devices can be configured as true LVDS transmit pairs. The PIO pairs on the bottom edge of these higher density devices have on-chip differential termination and also provide PCI support.



## **Output Register Block**

The output register block registers signals from the core of the device before they are passed to the sysIO buffers.

#### Left, Top, Bottom Edges

In SDR mode, D0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type register or latch.

In DDR generic mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the same clock is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-14 shows the output register block on the left, top and bottom edges.

Figure 2-14. MachXO2 Output Register Block Diagram (PIO on the Left, Top and Bottom Edges)



#### **Right Edge**

The output register block on the right edge is a superset of the output register on left, top and bottom edges of the device. In addition to supporting SDR and Generic DDR modes, the output register blocks for PIOs on the right edge include additional logic to support DDR-memory interfaces. Operation of this block is similar to that of the output register block on other edges.

In DDR memory mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the DQSW90 signal is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-15 shows the output register block on the right edge.



MachXO2-640U, MachXO2-1200/U, MachXO2-2000/U, MachXO2-4000 and MachXO2-7000 devices contain three types of sysIO buffer pairs.

#### 1. Left and Right sysIO Buffer Pairs

The sysIO buffer pairs in the left and right banks of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the left and right of the devices also have differential and referenced input buffers.

#### 2. Bottom sysIO Buffer Pairs

The sysIO buffer pairs in the bottom bank of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the bottom also have differential and referenced input buffers. Only the I/Os on the bottom banks have programmable PCI clamps and differential input termination. The PCI clamp is enabled after  $V_{CC}$  and  $V_{CCIO}$  are at valid operating levels and the device has been configured.

#### 3. Top sysIO Buffer Pairs

The sysIO buffer pairs in the top bank of the device consist of two single-ended output drivers and two singleended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the top also have differential and referenced I/O buffers. Half of the sysIO buffer pairs on the top edge have true differential outputs. The sysIO buffer pair comprising of the A and B PIOs in every PIC on the top edge have a differential output driver. The referenced input buffer can also be configured as a differential input buffer.

### Typical I/O Behavior During Power-up

The internal power-on-reset (POR) signal is deactivated when  $V_{CC}$  and  $V_{CCIO0}$  have reached  $V_{PORUP}$  level defined in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. After the POR signal is deactivated, the FPGA core logic becomes active. It is the user's responsibility to ensure that all  $V_{CCIO}$  banks are active with valid input logic levels to properly control the output logic states of all the I/O banks that are critical to the application. The default configuration of the I/O pins in a blank device is tri-state with a weak pulldown to GND (some pins such as PROGRAMN and the JTAG pins have weak pull-up to  $V_{CCIO}$  as the default functionality). The I/O pins will maintain the blank configuration until  $V_{CC}$  and  $V_{CCIO}$  (for I/O banks containing configuration I/Os) have reached  $V_{PORUP}$  levels at which time the I/Os will take on the user-configured settings only after a proper download/configuration.

### **Supported Standards**

The MachXO2 sysIO buffer supports both single-ended and differential standards. Single-ended standards can be further subdivided into LVCMOS, LVTTL, and PCI. The buffer supports the LVTTL, PCI, LVCMOS 1.2, 1.5, 1.8, 2.5, and 3.3 V standards. In the LVCMOS and LVTTL modes, the buffer has individually configurable options for drive strength, bus maintenance (weak pull-up, weak pull-down, bus-keeper latch or none) and open drain. BLVDS, MLVDS and LVPECL output emulation is supported on all devices. The MachXO2-640U, MachXO2-1200/U and higher devices support on-chip LVDS output buffers on approximately 50% of the I/Os on the top bank. Differential receivers for LVDS, BLVDS, MLVDS and LVPECL are supported on all banks of MachXO2 devices. PCI support is provided in the bottom bank of theMachXO2-640U, MachXO2-1200/U and higher density devices. Table 2-11 summarizes the I/O characteristics of the MachXO2 PLDs.

Tables 2-11 and 2-12 show the I/O standards (together with their supply and reference voltages) supported by the MachXO2 devices. For further information on utilizing the sysIO buffer to support a variety of standards please see TN1202, MachXO2 sysIO Usage Guide.



# **Configuration and Testing**

This section describes the configuration and testing features of the MachXO2 family.

## IEEE 1149.1-Compliant Boundary Scan Testability

All MachXO2 devices have boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: TDI, TDO, TCK and TMS. The test access port shares its power supply with V<sub>CCIO</sub> Bank 0 and can operate with LVCMOS3.3, 2.5, 1.8, 1.5, and 1.2 standards.

For more details on boundary scan test, see AN8066, Boundary Scan Testability with Lattice sysIO Capability and TN1087, Minimizing System Interruption During Configuration Using TransFR Technology.

## **Device Configuration**

All MachXO2 devices contain two ports that can be used for device configuration. The Test Access Port (TAP), which supports bit-wide configuration and the sysCONFIG port which supports serial configuration through I<sup>2</sup>C or SPI. The TAP supports both the IEEE Standard 1149.1 Boundary Scan specification and the IEEE Standard 1532 In-System Configuration specification. There are various ways to configure a MachXO2 device:

- 1. Internal Flash Download
- 2. JTAG
- 3. Standard Serial Peripheral Interface (Master SPI mode) interface to boot PROM memory
- 4. System microprocessor to drive a serial slave SPI port (SSPI mode)
- 5. Standard I<sup>2</sup>C Interface to system microprocessor

Upon power-up, the configuration SRAM is ready to be configured using the selected sysCONFIG port. Once a configuration port is selected, it will remain active throughout that configuration cycle. The IEEE 1149.1 port can be activated any time after power-up by sending the appropriate command through the TAP port. Optionally the device can run a CRC check upon entering the user mode. This will ensure that the device was configured correctly.

The sysCONFIG port has 10 dual-function pins which can be used as general purpose I/Os if they are not required for configuration. See TN1204, MachXO2 Programming and Configuration Usage Guide for more information about using the dual-use pins as general purpose I/Os.

Lattice design software uses proprietary compression technology to compress bit-streams for use in MachXO2 devices. Use of this technology allows Lattice to provide a lower cost solution. In the unlikely event that this technology is unable to compress bitstreams to fit into the amount of on-chip Flash memory, there are a variety of techniques that can be utilized to allow the bitstream to fit in the on-chip Flash memory. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

The Test Access Port (TAP) has five dual purpose pins (TDI, TDO, TMS, TCK and JTAGENB). These pins are dual function pins - TDI, TDO, TMS and TCK can be used as general purpose I/O if desired. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

#### TransFR (Transparent Field Reconfiguration)

TransFR is a unique Lattice technology that allows users to update their logic in the field without interrupting system operation using a simple push-button solution. For more details refer to TN1087, Minimizing System Interruption During Configuration Using TransFR Technology for details.



When implementing background programming of the on-chip Flash, care must be taken for the operation of the PLL. For devices that have two PLLs (XO2-2000U, -4000 and -7000), the system must put the RPLL (Right-side PLL) in reset state during the background Flash programming. More detailed description can be found in TN1204, MachXO2 Programming and Configuration Usage Guide.

#### Security and One-Time Programmable Mode (OTP)

For applications where security is important, the lack of an external bitstream provides a solution that is inherently more secure than SRAM-based FPGAs. This is further enhanced by device locking. MachXO2 devices contain security bits that, when set, prevent the readback of the SRAM configuration and non-volatile Flash memory spaces. The device can be in one of two modes:

- 1. Unlocked Readback of the SRAM configuration and non-volatile Flash memory spaces is allowed.
- 2. Permanently Locked The device is permanently locked.

Once set, the only way to clear the security bits is to erase the device. To further complement the security of the device, a One Time Programmable (OTP) mode is available. Once the device is set in this mode it is not possible to erase or re-program the Flash and SRAM OTP portions of the device. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

#### Dual Boot

MachXO2 devices can optionally boot from two patterns, a primary bitstream and a golden bitstream. If the primary bitstream is found to be corrupt while being downloaded into the SRAM, the device shall then automatically re-boot from the golden bitstream. Note that the primary bitstream must reside in the on-chip Flash. The golden image MUST reside in an external SPI Flash. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

#### Soft Error Detection

The SED feature is a CRC check of the SRAM cells after the device is configured. This check ensures that the SRAM cells were configured successfully. This feature is enabled by a configuration bit option. The Soft Error Detection can also be initiated in user mode via an input to the fabric. The clock for the Soft Error Detection circuit is generated using a dedicated divider. The undivided clock from the on-chip oscillator is the input to this divider. For low power applications users can switch off the Soft Error Detection circuit. For more details, refer to TN1206, MachXO2 Soft Error Detection Usage Guide.

## TraceID

Each MachXO2 device contains a unique (per device), TraceID that can be used for tracking purposes or for IP security applications. The TraceID is 64 bits long. Eight out of 64 bits are user-programmable, the remaining 56 bits are factory-programmed. The TraceID is accessible through the EFB WISHBONE interface and can also be accessed through the SPI, I<sup>2</sup>C, or JTAG interfaces.

## **Density Shifting**

The MachXO2 family has been designed to enable density migration within the same package. Furthermore, the architecture ensures a high success rate when performing design migration from lower density devices to higher density devices. In many cases, it is also possible to shift a lower utilization design targeted for a high-density device to a lower density device. However, the exact details of the final resource utilization will impact the likely success in each case. When migrating from lower to higher density or higher to lower density, ensure to review all the power supplies and NC pins of the chosen devices. For more details refer to the MachXO2 migration files.



# Power-On-Reset Voltage Levels<sup>1, 2, 3, 4, 5</sup>

Symbol	Parameter	Min.	Тур.	Max.	Units
V <sub>PORUP</sub>	Power-On-Reset ramp up trip point (band gap based circuit monitoring $V_{CCINT}$ and $V_{CCIO0})$	0.9	—	1.06	V
V <sub>PORUPEXT</sub>	Power-On-Reset ramp up trip point (band gap based circuit monitoring external $V_{CC}$ power supply)	1.5	_	2.1	V
V <sub>PORDNBG</sub>	Power-On-Reset ramp down trip point (band gap based circuit monitoring $V_{CCINT})$	0.75	_	0.93	V
V <sub>PORDNBGEXT</sub>	Power-On-Reset ramp down trip point (band gap based circuit monitoring $\mathrm{V}_{\mathrm{CC}}$ )	0.98	_	1.33	V
V <sub>PORDNSRAM</sub>	Power-On-Reset ramp down trip point (SRAM based circuit monitoring $V_{CCINT})$	_	0.6		V
V <sub>PORDNSRAMEXT</sub>	Power-On-Reset ramp down trip point (SRAM based circuit monitoring $\mathrm{V}_{\mathrm{CC}}$ )	_	0.96	—	V

1. These POR trip points are only provided for guidance. Device operation is only characterized for power supply voltages specified under recommended operating conditions.

2. For devices without voltage regulators V<sub>CCINT</sub> is the same as the V<sub>CC</sub> supply voltage. For devices with voltage regulators, V<sub>CCINT</sub> is regulated from the V<sub>CC</sub> supply voltage.

3. Note that V<sub>PORUP</sub> (min.) and V<sub>PORDNBG</sub> (max.) are in different process corners. For any given process corner V<sub>PORDNBG</sub> (max.) is always 12.0 mV below V<sub>PORUP</sub> (min.).

4. V<sub>PORUPEXT</sub> is for HC devices only. In these devices a separate POR circuit monitors the external V<sub>CC</sub> power supply.

5. V<sub>CCIO0</sub> does not have a Power-On-Reset ramp down trip point. V<sub>CCIO0</sub> must remain within the Recommended Operating Conditions to ensure proper operation.

# **Programming/Erase Specifications**

Symbol	Parameter	Min.	Max. <sup>1</sup>	Units
N <sub>PROGCYC</sub>	Flash Programming cycles per t <sub>RETENTION</sub>	—	10,000	Cycles
	Flash functional programming cycles	—	100,000	Oycles
t <sub>RETENTION</sub>	Data retention at 100 °C junction temperature	10	—	Years
	Data retention at 85 °C junction temperature	20	_	Teals

1. Maximum Flash memory reads are limited to 7.5E13 cycles over the lifetime of the product.

# Hot Socketing Specifications<sup>1, 2, 3</sup>

Symbol	Parameter	Condition	Max.	Units	
I <sub>DK</sub>	Input or I/O leakage Current	$0 < V_{IN} < V_{IH}$ (MAX)	+/-1000	μΑ	

1. Insensitive to sequence of  $V_{CC}$  and  $V_{CCIO}$ . However, assumes monotonic rise/fall rates for  $V_{CC}$  and  $V_{CCIO}$ .

2.  $0 < V_{CC} < V_{CC}$  (MAX),  $0 < V_{CCIO} < V_{CCIO}$  (MAX).

3. I<sub>DK</sub> is additive to I<sub>PU</sub>, I<sub>PD</sub> or I<sub>BH</sub>.

## **ESD Performance**

Please refer to the MachXO2 Product Family Qualification Summary for complete qualification data, including ESD performance.



# Programming and Erase Flash Supply Current – ZE Devices<sup>1, 2, 3, 4</sup>

Symbol	Parameter	Device	Typ.⁵	Units
		LCMXO2-256ZE	13	mA
		LCMXO2-640ZE	14	mA
	Core Power Supply	LCMXO2-1200ZE	15	mA
ICC		LCMXO2-2000ZE	17	mA
		LCMXO2-4000ZE	18	mA
		LCMXO2-7000ZE	20	mA
ICCIO	Bank Power Supply <sup>6</sup>	All devices	0	mA

1. For further information on supply current, please refer to TN1198, Power Estimation and Management for MachXO2 Devices.

2. Assumes all inputs are held at  $V_{\mbox{CCIO}}$  or GND and all outputs are tri-stated.

3. Typical user pattern.

4. JTAG programming is at 25 MHz.

5. TJ = 25 °C, power supplies at nominal voltage.

6. Per bank.  $V_{CCIO}$  = 2.5 V. Does not include pull-up/pull-down.



## LVDS Emulation

MachXO2 devices can support LVDS outputs via emulation (LVDS25E). The output is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all devices. The scheme shown in Figure 3-1 is one possible solution for LVDS standard implementation. Resistor values in Figure 3-1 are industry standard values for 1% resistors.





Note: All resistors are ±1%.

#### Table 3-1. LVDS25E DC Conditions

#### **Over Recommended Operating Conditions**

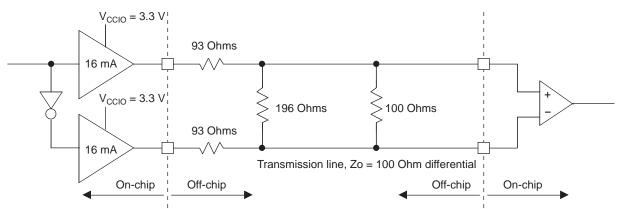
<b>_</b>									
Parameter	Description	Тур.	Units						
Z <sub>OUT</sub>	Output impedance	20	Ohms						
R <sub>S</sub>	Driver series resistor	158	Ohms						
R <sub>P</sub>	Driver parallel resistor	140	Ohms						
R <sub>T</sub>	Receiver termination	100	Ohms						
V <sub>OH</sub>	Output high voltage	1.43	V						
V <sub>OL</sub>	Output low voltage	1.07	V						
V <sub>OD</sub>	Output differential voltage	0.35	V						
V <sub>CM</sub>	Output common mode voltage	1.25	V						
Z <sub>BACK</sub>	Back impedance	100.5	Ohms						
I <sub>DC</sub>	DC output current	6.03	mA						



## LVPECL

The MachXO2 family supports the differential LVPECL standard through emulation. This output standard is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all the devices. The LVPECL input standard is supported by the LVDS differential input buffer. The scheme shown in Differential LVPECL is one possible solution for point-to-point signals.

#### Figure 3-3. Differential LVPECL



#### Table 3-3. LVPECL DC Conditions<sup>1</sup>

Symbol	Description	Nominal	Units
Z <sub>OUT</sub>	Output impedance	20	Ohms
R <sub>S</sub>	Driver series resistor	93	Ohms
R <sub>P</sub>	Driver parallel resistor	196	Ohms
R <sub>T</sub>	Receiver termination	100	Ohms
V <sub>OH</sub>	Output high voltage	2.05	V
V <sub>OL</sub>	Output low voltage	1.25	V
V <sub>OD</sub>	Output differential voltage	0.80	V
V <sub>CM</sub>	Output common mode voltage	1.65	V
Z <sub>BACK</sub>	BACK Back impedance		Ohms
DC	DC output current		mA

#### **Over Recommended Operating Conditions**

1. For input buffer, see LVDS table.

For further information on LVPECL, BLVDS and other differential interfaces please see details of additional technical documentation at the end of the data sheet.



			_	-6	_	5	_	4	
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units
Generic DDR	X2 Outputs with Clock and Data	Centered at Pin Using P	CLK Pin	for Cloc	k Input –	GDDRX	2_TX.EC	LK.Cen	tered <sup>9, 12</sup>
t <sub>DVB</sub>	Output Data Valid Before CLK Output	MachXO2-640U,	0.535	_	0.670	_	0.830	_	ns
t <sub>DVA</sub>	Output Data Valid After CLK Output		0.535	_	0.670	_	0.830	_	ns
f <sub>DATA</sub>	DDRX2 Serial Output Data Speed	MachXO2-1200/U and larger devices, top side only.		664	_	554	_	462	Mbps
f <sub>DDRX2</sub>	DDRX2 ECLK Frequency (minimum limited by PLL)			332	_	277	_	231	MHz
f <sub>SCLK</sub>	SCLK Frequency			166	—	139		116	MHz
Generic DDF	X4 Outputs with Clock and Data	Aligned at Pin Using P	CLK Pin	for Cloc	k Input	- GDDR	X4_TX.E	CLK.Ali	gned <sup>9, 12</sup>
t <sub>DIA</sub>	Output Data Invalid After CLK Output		_	0.200	_	0.215	_	0.230	ns
t <sub>DIB</sub>	Output Data Invalid Before CLK Output	MachXO2-640U, MachXO2-1200/U and		0.200	_	0.215	_	0.230	ns
f <sub>DATA</sub>	DDRX4 Serial Output Data Speed	larger devices, top side only.		756	_	630	_	524	Mbps
f <sub>DDRX4</sub>	DDRX4 ECLK Frequency		_	378	—	315	—	262	MHz
f <sub>SCLK</sub>	SCLK Frequency		_	95	—	79		66	MHz
Generic DDF	X4 Outputs with Clock and Data	Centered at Pin Using Po	CLK Pin	for Cloc	k Input –	GDDRX	4_TX.EC	LK.Cen	tered <sup>9, 12</sup>
t <sub>DVB</sub>	Output Data Valid Before CLK Output		0.455	_	0.570		0.710	—	ns
t <sub>DVA</sub>	Output Data Valid After CLK Output	MachXO2-640U,	0.455	_	0.570		0.710	_	ns
f <sub>DATA</sub>	DDRX4 Serial Output Data Speed	MachXO2-1200/U and larger devices, top side only.		756	_	630	_	524	Mbps
f <sub>DDRX4</sub>	DDRX4 ECLK Frequency (minimum limited by PLL)	ony.		378	_	315	_	262	MHz
f <sub>SCLK</sub>	SCLK Frequency		_	95	—	79	—	66	MHz
7:1 LVDS Ou	utputs - GDDR71_TX.ECLK.7:1	9, 12							
t <sub>DIB</sub>	Output Data Invalid Before CLK Output		_	0.160	_	0.180		0.200	ns
t <sub>DIA</sub>	Output Data Invalid After CLK Output	MachXO2-640U,		0.160	_	0.180	_	0.200	ns
f <sub>DATA</sub>	DDR71 Serial Output Data Speed	MachXO2-1200/U and larger devices, top side	_	756	_	630	_	524	Mbps
f <sub>DDR71</sub>	DDR71 ECLK Frequency	only.	_	378	_	315	_	262	MHz
fclkout	7:1 Output Clock Frequency (SCLK) (minimum limited by PLL)		_	108	_	90	_	75	MHz



# MachXO2 External Switching Characteristics – ZE Devices<sup>1, 2, 3, 4, 5, 6, 7</sup>

			-	-3	-	2	-	1	
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units
Clocks									
Primary Cloo	cks								
f <sub>MAX_PRI</sub> <sup>8</sup>	Frequency for Primary Clock Tree	All MachXO2 devices	_	150	_	125	—	104	MHz
t <sub>W_PRI</sub>	Clock Pulse Width for Primary Clock	All MachXO2 devices	1.00	_	1.20	_	1.40	_	ns
		MachXO2-256ZE	—	1250		1272	—	1296	ps
		MachXO2-640ZE		1161		1183	—	1206	ps
	Primary Clock Skew Within a	MachXO2-1200ZE		1213		1267	—	1322	ps
<sup>t</sup> SKEW_PRI	Device	MachXO2-2000ZE		1204		1250	—	1296	ps
		MachXO2-4000ZE		1195		1233	—	1269	ps
		MachXO2-7000ZE		1243		1268	—	1296	ps
Edge Clock									
f <sub>MAX_EDGE<sup>8</sup></sub>	Frequency for Edge Clock	MachXO2-1200 and larger devices	_	210	_	175	_	146	MHz
Pin-LUT-Pin	Propagation Delay			1	1				1
t <sub>PD</sub>	Best case propagation delay through one LUT-4	All MachXO2 devices	_	9.35	_	9.78	_	10.21	ns
General I/O I	Pin Parameters (Using Primary	Clock without PLL)	1	1	1	1		1	
		MachXO2-256ZE		10.46	—	10.86	—	11.25	ns
		MachXO2-640ZE		10.52		10.92	—	11.32	ns
	Clock to Output – PIO Output	MachXO2-1200ZE		11.24		11.68	—	12.12	ns
t <sub>CO</sub>	Register	MachXO2-2000ZE		11.27		11.71	—	12.16	ns
		MachXO2-4000ZE		11.28		11.78	—	12.28	ns
		MachXO2-7000ZE	—	11.22		11.76	—	12.30	ns
		MachXO2-256ZE	-0.21		-0.21	—	-0.21	—	ns
		MachXO2-640ZE	-0.22	—	-0.22	—	-0.22	—	ns
	Clock to Data Setup – PIO	MachXO2-1200ZE	-0.25	—	-0.25	—	-0.25	—	ns
t <sub>SU</sub>	Input Register	MachXO2-2000ZE	-0.27	—	-0.27	—	-0.27	—	ns
		MachXO2-4000ZE	-0.31	—	-0.31		-0.31		ns
		MachXO2-7000ZE	-0.33	—	-0.33		-0.33		ns
		MachXO2-256ZE	3.96		4.25	_	4.65	_	ns
		MachXO2-640ZE	4.01		4.31	—	4.71	—	ns
+	Clock to Data Hold – PIO Input	MachXO2-1200ZE	3.95		4.29	_	4.73	_	ns
t <sub>H</sub>	Register	MachXO2-2000ZE	3.94	—	4.29	—	4.74	—	ns
		MachXO2-4000ZE	3.96		4.36	—	4.87	—	ns
		MachXO2-7000ZE	3.93		4.37	—	4.91		ns
		IVIACHAU2-7000ZE	3.93	—	4.37		4.91		

**Over Recommended Operating Conditions** 



			-	-3	-	-2	- 1	1	
Parameter	Description	Device	Min.	Max.	Min.	Max.	Min.	Max.	Units
		MachXO2-1200ZE	0.66		0.68		0.80		ns
		MachXO2-2000ZE	0.68	—	0.70	—	0.83	—	ns
t <sub>HPLL</sub>		MachXO2-4000ZE	0.68	—	0.71	—	0.84	—	ns
		MachXO2-7000ZE	0.73	—	0.74	—	0.87	—	ns
-		MachXO2-1200ZE	5.14	—	5.69	—	6.20	—	ns
	Clock to Data Setup – PIO	MachXO2-2000ZE	5.11	—	5.67	—	6.17	—	ns
<sup>t</sup> SU_DELPLL	Input Register with Data Input Delay	MachXO2-4000ZE	5.27	—	5.84		6.35	—	ns
		MachXO2-7000ZE	5.15	—	5.71	—	6.23	—	ns
-		MachXO2-1200ZE	-1.36	—	-1.36	—	-1.36	—	ns
	Clock to Data Hold – PIO Input	MachXO2-2000ZE	-1.35		-1.35		-1.35		ns
<sup>t</sup> H_DELPLL		MachXO2-4000ZE	-1.43		-1.43		-1.43		ns
		MachXO2-7000ZE	-1.41		-1.41		-1.41		ns
Generic DDR	X1 Inputs with Clock and Data A	ligned at Pin Using P	CLK Pin	for Cloc	k Input -	- GDDR)	(1_RX.S	CLK.Ali	gned <sup>9, 12</sup>
t <sub>DVA</sub>	Input Data Valid After CLK		—	0.382		0.401	—	0.417	UI
t <sub>DVE</sub>	Input Data Hold After CLK	All MachXO2	0.670	—	0.684		0.693	—	UI
f <sub>DATA</sub>	DDRX1 Input Data Speed	devices, all sides	_	140		116	—	98	Mbps
f <sub>DDRX1</sub>	DDRX1 SCLK Frequency		_	70		58	—	49	MHz
	Generic DDRX1 Inputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input – GDDRX1_RX.SCLK.Centered <sup>9, 12</sup>								
t <sub>SU</sub>	Input Data Setup Before CLK		1.319		1.412		1.462		ns
t <sub>HO</sub>	Input Data Hold After CLK	All MachXO2	0.717	_	1.010		1.340		ns
f <sub>DATA</sub>	DDRX1 Input Data Speed	devices, all sides	_	140		116	—	98	Mbps
f <sub>DDRX1</sub>	DDRX1 SCLK Frequency		_	70		58	—	49	MHz
	X2 Inputs with Clock and Data A	ligned at Pin Using P	LK Pin	for Cloc	k Input -	GDDR	2_RX.E	CLK.Ali	gned <sup>9, 12</sup>
t <sub>DVA</sub>	Input Data Valid After CLK		_	0.361		0.346	—	0.334	UI
t <sub>DVE</sub>	Input Data Hold After CLK	MachXO2-640U,	0.602		0.625		0.648		UI
f <sub>DATA</sub>	DDRX2 Serial Input Data Speed	MachXO2-1200/U and larger devices,	_	280	_	234	_	194	Mbps
f <sub>DDRX2</sub>	DDRX2 ECLK Frequency	bottom side only <sup>11</sup>	_	140		117	—	97	MHz
f <sub>SCLK</sub>	SCLK Frequency		_	70		59	—	49	MHz
	X2 Inputs with Clock and Data Ce	entered at Pin Using P	LK Pin f	for Clock	Input –	GDDRX	2_RX.EC	LK.Cen	tered <sup>9, 12</sup>
t <sub>SU</sub>	Input Data Setup Before CLK		0.472		0.672		0.865		ns
t <sub>HO</sub>	Input Data Hold After CLK	MachXO2-640U,	0.363	_	0.501		0.743		ns
f <sub>DATA</sub>	DDRX2 Serial Input Data Speed	MachXO2-0400, MachXO2-1200/U and larger devices,		280	_	234	_	194	Mbps
f <sub>DDRX2</sub>	DDRX2 ECLK Frequency	bottom side only <sup>11</sup>		140		117	_	97	MHz
f <sub>SCLK</sub>	SCLK Frequency			70		59	_	49	MHz
	4 Inputs with Clock and Data A	ligned at Pin Using PC	LK Pin	for Cloc	k Input -	GDDRX	4_RX.E	CLK.Ali	gned <sup>9, 12</sup>
t <sub>DVA</sub>	Input Data Valid After ECLK		_	0.307		0.316	_	0.326	UI
t <sub>DVE</sub>	Input Data Hold After ECLK	MachXO2-640U,	0.662		0.650		0.649	_	UI
f <sub>DATA</sub>	DDRX4 Serial Input Data Speed	MachXO2-1200/U and larger devices,	—	420	_	352	_	292	Mbps
f <sub>DDRX4</sub>	DDRX4 ECLK Frequency	bottom side only <sup>11</sup>	_	210		176	_	146	MHz
f <sub>SCLK</sub>	SCLK Frequency		<u> </u>	53	_	44	—	37	MHz
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	MachXO2-1200					MachXO2-1200U
	100 TQFP	132 csBGA	144 TQFP	25 WLCSP	32 QFN <sup>1</sup>	256 ftBGA
General Purpose I/O per Bank	•					
Bank 0	18	25	27	11	9	50
Bank 1	21	26	26	0	2	52
Bank 2	20	28	28	7	9	52
Bank 3	20	25	26	0	2	16
Bank 4	0	0	0	0	0	16
Bank 5	0	0	0	0	0	20
Total General Purpose Single Ended I/O	79	104	107	18	22	206
Differential I/O per Bank						
Bank 0	9	13	14	5	4	25
Bank 1	10	13	13	0	1	26
Bank 2	10	14	14	2	4	26
Bank 3	10	12	13	0	1	8
Bank 4	0	0	0	0	0	8
Bank 5	0	0	0	0	0	10
Total General Purpose Differential I/O	39	52	54	7	10	103
Dual Function I/O	31	33	33	18	22	33
High-speed Differential I/O						
Bank 0	4	7	7	0	0	14
Gearboxes						
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	4	7	7	0	0	14
Number of 7:1 or 8:1 Input Gearbox Avail- able (Bank 2)	5	7	7	0	2	14
DQS Groups						
Bank 1	1	2	2	0	0	2
VCCIO Pins						
Bank 0	2	3	3	1	2	4
Bank 1	2	3	3	0	1	4
Bank 2	2	3	3	1	2	4
Bank 3	3	3	3	0	1	1
Bank 4	0	0	0	0	0	2
Bank 5	0	0	0	0	0	1
VCC	2	4	4	2	2	8
GND	8	10	12	2	2	24
NC	1	1	8	0	0	1
Reserved for Configuration	1	1	1	1	1	1
Total Count of Bonded Pins	100	132	144	25	32	256
1. Lattice recommends soldering the centra						

1. Lattice recommends soldering the central thermal pad onto the top PCB ground for improved thermal resistance.



Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-2000ZE-1UWG49ITR1	2112	1.2 V	-1	Halogen-Free WLCSP	49	IND
LCMXO2-2000ZE-1UWG49ITR50 <sup>3</sup>	2112	1.2 V	-1	Halogen-Free WLCSP	49	IND
LCMXO2-2000ZE-1UWG49ITR1K <sup>2</sup>	2112	1.2 V	-1	Halogen-Free WLCSP	49	IND
LCMXO2-2000ZE-1TG100I	2112	1.2 V	-1	Halogen-Free TQFP	100	IND
LCMXO2-2000ZE-2TG100I	2112	1.2 V	-2	Halogen-Free TQFP	100	IND
LCMXO2-2000ZE-3TG100I	2112	1.2 V	-3	Halogen-Free TQFP	100	IND
LCMXO2-2000ZE-1MG132I	2112	1.2 V	-1	Halogen-Free csBGA	132	IND
LCMXO2-2000ZE-2MG132I	2112	1.2 V	-2	Halogen-Free csBGA	132	IND
LCMXO2-2000ZE-3MG132I	2112	1.2 V	-3	Halogen-Free csBGA	132	IND
LCMXO2-2000ZE-1TG144I	2112	1.2 V	-1	Halogen-Free TQFP	144	IND
LCMXO2-2000ZE-2TG144I	2112	1.2 V	-2	Halogen-Free TQFP	144	IND
LCMXO2-2000ZE-3TG144I	2112	1.2 V	-3	Halogen-Free TQFP	144	IND
LCMXO2-2000ZE-1BG256I	2112	1.2 V	-1	Halogen-Free caBGA	256	IND
LCMXO2-2000ZE-2BG256I	2112	1.2 V	-2	Halogen-Free caBGA	256	IND
LCMXO2-2000ZE-3BG256I	2112	1.2 V	-3	Halogen-Free caBGA	256	IND
LCMXO2-2000ZE-1FTG256I	2112	1.2 V	-1	Halogen-Free ftBGA	256	IND
LCMXO2-2000ZE-2FTG256I	2112	1.2 V	-2	Halogen-Free ftBGA	256	IND
LCMXO2-2000ZE-3FTG256I	2112	1.2 V	-3	Halogen-Free ftBGA	256	IND

1. This part number has a tape and reel quantity of 5,000 units with a minimum order quantity of 10,000 units. Order quantities must be in increments of 5,000 units. For example, a 10,000 unit order will be shipped in two reels with one reel containing 5,000 units and the other reel with less than 5,000 units (depending on test yields). Unserviced backlog will be canceled.

2. This part number has a tape and reel quantity of 1,000 units with a minimum order quantity of 1,000. Order quantities must be in increments of 1,000 units. For example, a 5,000 unit order will be shipped as 5 reels of 1000 units each.

3. This part number has a tape and reel quantity of 50 units with a minimum order quantity of 50. Order quantities must be in increments of 50 units. For example, a 1,000 unit order will be shipped as 20 reels of 50 units each.



Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-4000HC-4QN84I	4320	2.5 V / 3.3 V	-4	Halogen-Free QFN	84	IND
LCMXO2-4000HC-5QN84I	4320	2.5 V / 3.3 V	-5	Halogen-Free QFN	84	IND
LCMXO2-4000HC-6QN84I	4320	2.5 V / 3.3 V	-6	Halogen-Free QFN	84	IND
LCMXO2-4000HC-4TG144I	4320	2.5 V / 3.3 V	-4	Halogen-Free TQFP	144	IND
LCMXO2-4000HC-5TG144I	4320	2.5 V / 3.3 V	-5	Halogen-Free TQFP	144	IND
LCMXO2-4000HC-6TG144I	4320	2.5 V / 3.3 V	-6	Halogen-Free TQFP	144	IND
LCMXO2-4000HC-4MG132I	4320	2.5 V / 3.3 V	-4	Halogen-Free csBGA	132	IND
LCMXO2-4000HC-5MG132I	4320	2.5 V / 3.3 V	-5	Halogen-Free csBGA	132	IND
LCMXO2-4000HC-6MG132I	4320	2.5 V / 3.3 V	-6	Halogen-Free csBGA	132	IND
LCMXO2-4000HC-4BG256I	4320	2.5 V / 3.3 V	-4	Halogen-Free caBGA	256	IND
LCMXO2-4000HC-5BG256I	4320	2.5 V / 3.3 V	-5	Halogen-Free caBGA	256	IND
LCMXO2-4000HC-6BG256I	4320	2.5 V / 3.3 V	-6	Halogen-Free caBGA	256	IND
LCMXO2-4000HC-4FTG256I	4320	2.5 V / 3.3 V	-4	Halogen-Free ftBGA	256	IND
LCMXO2-4000HC-5FTG256I	4320	2.5 V / 3.3 V	-5	Halogen-Free ftBGA	256	IND
LCMXO2-4000HC-6FTG256I	4320	2.5 V / 3.3 V	-6	Halogen-Free ftBGA	256	IND
LCMXO2-4000HC-4BG332I	4320	2.5 V / 3.3 V	-4	Halogen-Free caBGA	332	IND
LCMXO2-4000HC-5BG332I	4320	2.5 V / 3.3 V	-5	Halogen-Free caBGA	332	IND
LCMXO2-4000HC-6BG332I	4320	2.5 V / 3.3 V	-6	Halogen-Free caBGA	332	IND
LCMXO2-4000HC-4FG484I	4320	2.5 V / 3.3 V	-4	Halogen-Free fpBGA	484	IND
LCMXO2-4000HC-5FG484I	4320	2.5 V / 3.3 V	-5	Halogen-Free fpBGA	484	IND
LCMXO2-4000HC-6FG484I	4320	2.5 V / 3.3 V	-6	Halogen-Free fpBGA	484	IND

Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-7000HC-4TG144I	6864	2.5 V / 3.3 V	-4	Halogen-Free TQFP	144	IND
LCMXO2-7000HC-5TG144I	6864	2.5 V / 3.3 V	-5	Halogen-Free TQFP	144	IND
LCMXO2-7000HC-6TG144I	6864	2.5 V / 3.3 V	-6	Halogen-Free TQFP	144	IND
LCMXO2-7000HC-4BG256I	6864	2.5 V / 3.3 V	-4	Halogen-Free caBGA	256	IND
LCMXO2-7000HC-5BG256I	6864	2.5 V / 3.3 V	-5	Halogen-Free caBGA	256	IND
LCMXO2-7000HC-6BG256I	6864	2.5 V / 3.3 V	-6	Halogen-Free caBGA	256	IND
LCMXO2-7000HC-4FTG256I	6864	2.5 V / 3.3 V	-4	Halogen-Free ftBGA	256	IND
LCMXO2-7000HC-5FTG256I	6864	2.5 V / 3.3 V	-5	Halogen-Free ftBGA	256	IND
LCMXO2-7000HC-6FTG256I	6864	2.5 V / 3.3 V	-6	Halogen-Free ftBGA	256	IND
LCMXO2-7000HC-4BG332I	6864	2.5 V / 3.3 V	-4	Halogen-Free caBGA	332	IND
LCMXO2-7000HC-5BG332I	6864	2.5 V / 3.3 V	-5	Halogen-Free caBGA	332	IND
LCMXO2-7000HC-6BG332I	6864	2.5 V / 3.3 V	-6	Halogen-Free caBGA	332	IND
LCMXO2-7000HC-4FG400I	6864	2.5 V / 3.3 V	-4	Halogen-Free fpBGA	400	IND
LCMXO2-7000HC-5FG400I	6864	2.5 V / 3.3 V	-5	Halogen-Free fpBGA	400	IND
LCMXO2-7000HC-6FG400I	6864	2.5 V / 3.3 V	-6	Halogen-Free fpBGA	400	IND
LCMXO2-7000HC-4FG484I	6864	2.5 V / 3.3 V	-4	Halogen-Free fpBGA	484	IND
LCMXO2-7000HC-5FG484I	6864	2.5 V / 3.3 V	-5	Halogen-Free fpBGA	484	IND
LCMXO2-7000HC-6FG484I	6864	2.5 V / 3.3 V	-6	Halogen-Free fpBGA	484	IND



Date	Version	Section	Change Summary
May 2016	3.2	All	Moved designation for 84 QFN package information from 'Advanced' to 'Final'.
	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Added 'Advanced' 48 QFN package. — Revised footnote 6. — Added footnote 9.	
		DC and Switching Characteristics	Updated the MachXO2 External Switching Characteristics – HC/HE Devices section. Added footnote 12.
			Updated the MachXO2 External Switching Characteristics – ZE Devices section. Added footnote 12.
		Pinout Information	Updated the Signal Descriptions section. Added information on GND signal.
			Updated the Pinout Information Summary section. — Added 'Advanced' MachXO2-256 48 QFN values. — Added 'Advanced' MachXO2-640 48 QFN values. — Added footnote to GND. — Added footnotes 2 and 3.
		Ordering Information	Updated the MachXO2 Part Number Description section. Added 'Advanced' SG48 package and revised footnote.
			Updated the Ordering Information section. — Added part numbers for 'Advanced' QFN 48 package.
March 2016	March 2016 3.1	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Added 32 QFN value for XO2-1200. — Added 84 QFN (7 mm x 7 mm, 0.5 mm) package. — Modified package name to 100-pin TQFP. — Modified package name to 144-pin TQFP. — Added footnote.
		Architecture	Updated the Typical I/O Behavior During Power-up section. Removed reference to TN1202.
		DC and Switching Characteristics	Updated the sysCONFIG Port Timing Specifications section. Revised t <sub>DPPDONE</sub> and t <sub>DPPINIT</sub> Max. values per PCN 03A-16, released March 2016.
		Pinout Information	Updated the Pinout Information Summary section. — Added MachXO2-1200 32 QFN values. — Added 'Advanced' MachXO2-4000 84 QFN values.
		Ordering Information	Updated the MachXO2 Part Number Description section. Added 'Advanced' QN84 package and footnote.
			Updated the Ordering Information section. — Added part numbers for 1280 LUTs QFN 32 package. — Added part numbers for 4320 LUTs QFN 84 package.
March 2015	March 2015 3.0	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Changed 64-ball ucBGA dimension.
		Architecture	Updated the Device Configuration section. Added JTAGENB to TAP dual purpose pins.



Image: space with the second secon	Date	Version	Section	Change Summary
Guide table.     Architecture   Added information to Standby Mode and Power Saving Options section.     Pinout Information   Added the XO2-2000 49 WLCSP in the Pinout Information Summary table.     Ordering Information   Added the XO2-2000 2E in the Pinout Information Summary table.     Ordering Information   Added the XO2-2000ZE-1UWG49CTR in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging section.     Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section.   Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section.     December 2013   02.3   Architecture   Updated Information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section.     DC and Switching   Updated footnote 4 in sysIO Single-Ended DC Electrical Characteristics table; Updated V <sub>IL</sub> Max. (V) data for LVCMOS 25 and LVCMOS 28.     Updated V <sub>OS</sub> test condition in sysIO Differential Electrical Characteristics - LVDS table.   Updated Supported Input Standards table.     DC and Switching   Updated Power-On-Reset Voltage Levels table.   Updated Supported Input Standards table.     June 2013   02.1   Architecture   Architecture Overview – Added information on the state of the register on power up and after configuration.     June 2013   02.1   Architecture   Architec	May 2014	2.5	Architecture	Updated TransFR description for PLL use during background Flash
Image: section of the sectio	February 2014	02.4	Introduction	
Image: series of the series			Architecture	
Added and LCMXO2-2000ZE-1UWG49CTR in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging section.     Added and LCMXO2-2000ZE-1UWG49ITR in Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section.     December 2013   02.3     Architecture   Updated information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section.     DC and Switching Characteristics   Updated Static Supply Current – ZE Devices table.     Updated footnote 4 in sysIO Single-Ended DC Electrical Characteris tics table; Updated V <sub>IL</sub> Max. (V) data for LVCMOS 25 and LVCMOS 28.     Updated Vos test condition in sysIO Differential Electrical Characteri- istics - LVDS table.     September 2013   02.2     Oz and Switching Characteristics   Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.     Removed information on PDPR memory in RAM Mode section.   Updated Supported Input Standards table.     June 2013   02.1   Architecture   Architecture Overview – Added information on the state of the regis- ter on power up and after configuration.     sysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOC KPLL Timing table.   Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.			Pinout Information	Added the XO2-2000 49 WLCSP in the Pinout Information Summary table.
Image: bit is a series of the serie			Ordering Information	Added UW49 package in MachXO2 Part Number Description.
Industrial Grade Devices, Halogen Free (RoHS) Packaging section.     December 2013   02.3   Architecture   Updated information on CLKOS output divider in sysCLOCK Phase Locked Loops (PLLs) section.     DC and Switching Characteristics   Updated Static Supply Current – ZE Devices table.   Updated footnote 4 in sysIO Single-Ended DC Electrical Characteris tics table; Updated V <sub>IL</sub> Max. (V) data for LVCMOS 25 and LVCMOS 28.     September 2013   02.2   Architecture   Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.     Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   Removed information on PDPR memory in RAM Mode section.     Updated Supported Input Standards table.   Updated Power-On-Reset Voltage Levels table.     June 2013   02.1   Architecture   Architecture Overview – Added information on the state of the register on power up and after configuration.     SysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table.   DC and Switching Characteristics   Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – ED Povices and the MachXO2 External Switching Characteristics – ZE Devices tables.				Commercial Grade Devices, Halogen Free (RoHS) Packaging sec-
DC and Switching Characteristics   Updated Static Supply Current – ZE Devices table.     Updated footnote 4 in sysIO Single-Ended DC Electrical Characteristics table; Updated footnote 4 in sysIO Single-Ended DC Electrical Characteristics table; Updated V <sub>IL</sub> Max. (V) data for LVCMOS 25 and LVCMOS 28.     September 2013   02.2   Architecture   Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.     Removed information on PDPR memory in RAM Mode section.   Updated Supported Input Standards table.     June 2013   02.1   Architecture   Architecture Overview – Added information on the state of the register on power up and after configuration.     sysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table.   DC and Switching Characteristics     DC and Switching Characteristics   Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – ZE Devices tables.				
September 2013 02.2 Architecture Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13. Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Rective Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Architecture Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Architecture Overview – Added information on PDPR memory in RAM Mode section.   Updated Power-On-Reset Voltage Levels table. Updated Power-On-Reset Voltage Levels table.   June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration.   sysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table. Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.	December 2013	December 2013 02.3	Architecture	
September 2013 02.2 Architecture Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13. Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   June 2013 02.1 Architecture Architecture Overview – Added information on PDPR memory in RAM Mode section.   Updated Supported Input Standards table. Updated Power-On-Reset Voltage Levels table.   June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration.   sysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table. Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – ZE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.			Updated Static Supply Current – ZE Devices table.	
September 2013 02.2 Architecture Removed I <sup>2</sup> C Clock-Stretching feature per PCN #10A-13.   Removed information on PDPR memory in RAM Mode section. Updated Supported Input Standards table.   DC and Switching Characteristics Updated Power-On-Reset Voltage Levels table.   June 2013 02.1 Architecture Architecture Overview – Added information on the state of the register on power up and after configuration.   SysCLOCK Phase Locked Loops (PLLs) section – Added missing cross reference to sysCLOCK PLL Timing table. DC and Switching Characteristics   DC and Switching Characteristics Added slew rate information to footnote 2 of the MachXO2 External Switching Characteristics – HC/HE Devices and the MachXO2 External Switching Characteristics – ZE Devices tables.				
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Power-On-Reset Voltage Levels table – Added symbols.				Switching Characteristics - HC/HE Devices and the MachXO2 Exter-
				Power-On-Reset Voltage Levels table – Added symbols.



Date	Version	Section	Change Summary
January 2013	02.0	Introduction	Updated the total number IOs to include JTAGENB.
		Architecture	Supported Output Standards table – Added 3.3 $V_{CCIO}$ (Typ.) to LVDS row.
			Changed SRAM CRC Error Detection to Soft Error Detection.
		DC and Switching Characteristics	Power Supply Ramp Rates table – Updated Units column for t <sub>RAMP</sub> symbol.
			Added new Maximum sysIO Buffer Performance table.
			sysCLOCK PLL Timing table – Updated Min. column values for $f_{\rm IN}, f_{\rm OUT}, f_{\rm OUT2}$ and $f_{\rm PFD}$ parameters. Added $t_{\rm SPO}$ parameter. Updated footnote 6.
			MachXO2 Oscillator Output Frequency table – Updated symbol name
			for t <sub>STABLEOSC</sub> .
			DC Electrical Characteristics table – Updated conditions for ${\rm I}_{\rm IL,}~{\rm I}_{\rm IH}$ symbols.
			Corrected parameters tDQVBS and tDQVAS
			Corrected MachXO2 ZE parameters tDVADQ and tDVEDQ
		Pinout Information	Included the MachXO2-4000HE 184 csBGA package.
		Ordering Information	Updated part number.
April 2012	01.9	Architecture	Removed references to TN1200.
		Ordering Information	Updated the Device Status portion of the MachXO2 Part Number Description to include the 50 parts per reel for the WLCSP package.
			Added new part number and footnote 2 for LCMXO2-1200ZE- 1UWG25ITR50.
			Updated footnote 1 for LCMXO2-1200ZE-1UWG25ITR.
		Supplemental Information	Removed references to TN1200.
March 2012	01.8	Introduction	Added 32 QFN packaging information to Features bullets and MachXO2 Family Selection Guide table.
		DC and Switching Characteristics	Changed 'STANDBY' to 'USERSTDBY' in Standby Mode timing dia- gram.
	Pinout Information	Removed footnote from Pin Information Summary tables.	
			Added 32 QFN package to Pin Information Summary table.
		Ordering Information	Updated Part Number Description and Ordering Information tables for 32 QFN package.
		Updated topside mark diagram in the Ordering Information section.	



Date	Version	Section	Change Summary
February 2012	01.7	All	Updated document with new corporate logo.
	01.6	—	Data sheet status changed from preliminary to final.
		Introduction	MachXO2 Family Selection Guide table – Removed references to 49-ball WLCSP.
		DC and Switching Characteristics	Updated Flash Download Time table.
			Modified Storage Temperature in the Absolute Maximum Ratings section.
			Updated I <sub>DK</sub> max in Hot Socket Specifications table.
			Modified Static Supply Current tables for ZE and HC/HE devices.
			Updated Power Supply Ramp Rates table.
			Updated Programming and Erase Supply Current tables.
			Updated data in the External Switching Characteristics table.
			Corrected Absolute Maximum Ratings for Dedicated Input Voltage Applied for LCMXO2 HC.
			DC Electrical Characteristics table – Minor corrections to conditions for $\mathbf{I}_{IL},  \mathbf{I}_{IH.}$
		Pinout Information	Removed references to 49-ball WLCSP.
			Signal Descriptions table – Updated description for GND, VCC, and VCCIOx.
			Updated Pin Information Summary table – Number of VCCIOs, GNDs, VCCs, and Total Count of Bonded Pins for MachXO2-256, 640, and 640U and Dual Function I/O for MachXO2-4000 332caBGA.
		Ordering Information	Removed references to 49-ball WLCSP
August 2011	01.5	DC and Switching Characteristics	Updated ESD information.
		Ordering Information	Updated footnote for ordering WLCSP devices.
	01.4	Architecture	Updated information in Clock/Control Distribution Network and sys- CLOCK Phase Locked Loops (PLLs).
		DC and Switching Characteristics	Updated ${\rm I}_{\rm IL}$ and ${\rm I}_{\rm IH}$ conditions in the DC Electrical Characteristics table.
		Pinout Information	Included number of 7:1 and 8:1 gearboxes (input and output) in the pin information summary tables.
			Updated Pin Information Summary table: Dual Function I/O, DQS Groups Bank 1, Total General Purpose Single-Ended I/O, Differential I/O Per Bank, Total Count of Bonded Pins, Gearboxes.
			Added column of data for MachXO2-2000 49 WLCSP.
	Ordering Information	Updated R1 Device Specifications text section with information on migration from MachXO2-1200-R1 to Standard (non-R1) devices.	
		Corrected Supply Voltage typo for part numbers: LCMX02-2000UHE- 4FG484I, LCMX02-2000UHE-5FG484I, LCMX02-2000UHE- 6FG484I.	
			Added footnote for WLCSP package parts.
		Supplemental Information	Removed reference to Stand-alone Power Calculator for MachXO2 Devices. Added reference to AN8086, Designing for Migration from MachXO2-1200-R1 to Standard (non-R1) Devices.